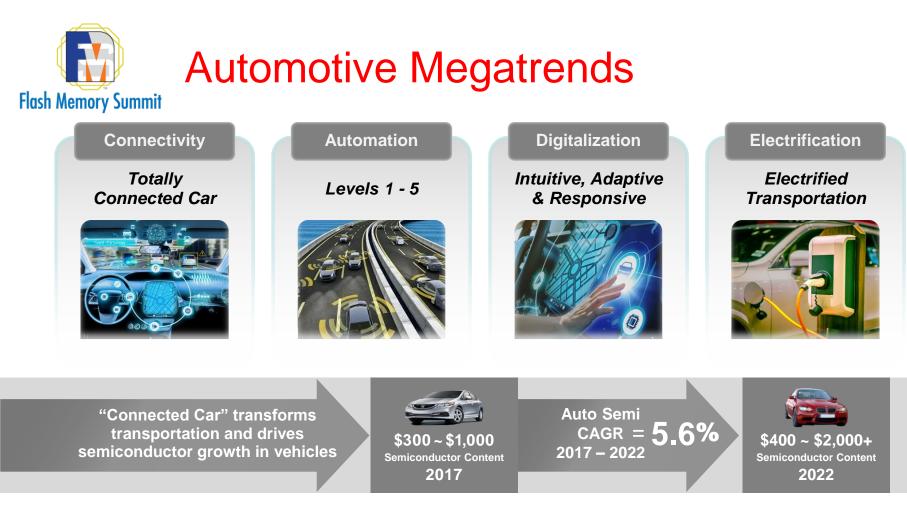


## Secure F-RAM for Event Data Recording in ADAS Systems

**Douglas Mitchell** 

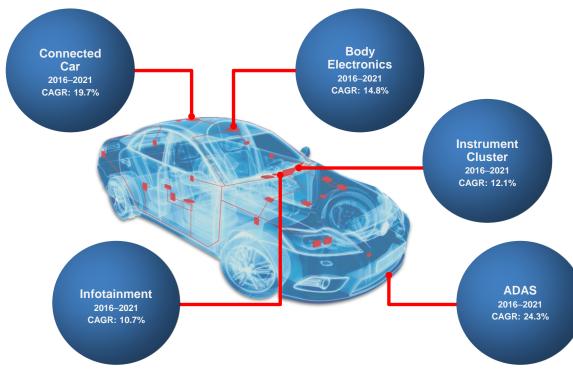


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## **Electronics Content**



## Automotive Infotainment System Trends

PAST Traditional Infotainment AM/FM Radio + CD + Navigation Separated ECU systems



NOW Connected Infotainment Wireless connectivity + Intelligent HMI Separated ECU systems



000000000

NEXT Integrated Cockpit

Intelligent Connectivity + Multiple displays + More personalization

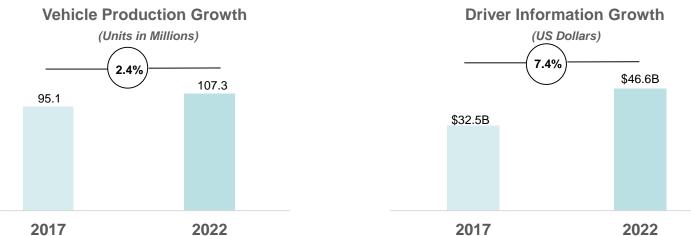
Single ECU system





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- Smart Phone-based and wireless-connected infotainment replacing traditional embedded system
- HMI solution trend towards to large display and multimodal interaction
- USB-C is everywhere in peripherals for mobile phones and PCs and now emerging in automotive
- Automotive manufacturers are pushing for initial Boot (Splash Screen) with fast NOR Flash to meet "Instanton" required by certain features (backup cameras, chimes, cluster displays)

### Driver Information\* market growing significantly faster than underlying vehicle production



## **REGULATIONS CONCERNING EDRs**

- NA NHTSA .
  - Regulations for required data elements for conventional Airbag module black boxes.
  - <u>https://www.law.cornell.edu/cfr/text/49/part-563</u>
  - https://www.nhtsa.gov/

### EU – EC Europa

- https://ec.europa.eu/transport/road\_safety/specialist/knowledge/esave/esafety\_measures\_known\_safety\_effects/black\_boxes\_in\_vehicle\_data\_recorders\_en
- Conclusions from the stakeholder meeting to make EDR mandatory in EU. Consensus is to make ADAS active safety data also to be made mandatory to be logged in addition to conventional black box parameters defined in NHTSA part 563.
- <u>https://ec.europa.eu/transport/road\_safety/sites/roadsafety/files/pdf/edr05062014/summary\_and\_conclusions.pdf</u>



## Gen1 EDRs in light duty vehicles for >40 yrs

- Air bag deployment timing
- Supplemental inflatable restraint (SIR) lamp status
- Longitudinal acceleration
- Seat belt status
- Limited vehicle sensor status (what triggered the event)





Next generations (1999+)

- Vehicle speed, engine RPM, percent throttle, service brake switch circuit status
- Accelerator position, transmission gear status, ABS activity, stability control status, traction control activity, yaw rate, steering wheel angle, individual wheel speed, cruise control status, etc.





### NHTSA-2006-25666

- Rule defining parameters to be recorded after 2012
- By model year 2013 96% of new passenger vehicles were EDR-equipped



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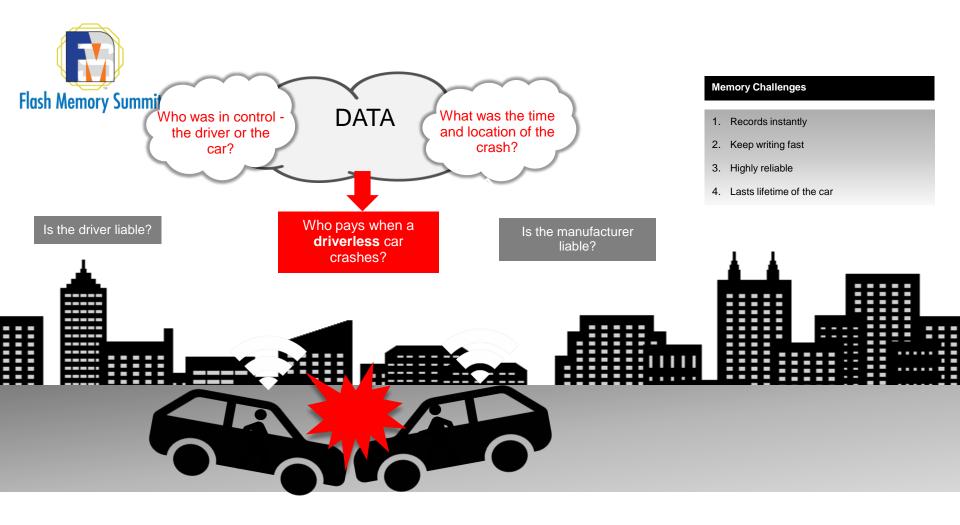


- So...why do we need EDRs?
  - Data forensics!
  - Post mortem analysis!

• What does the future hold?



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# **Design Challenges**

- Semi-Autonomous, Autonomous vehicles
- Sensors; Cameras, Lidar, Radar, Ultrasonic
- GPS
- V2X
- Signal integrity/interference/spoofing

These sources add to the challenges of ensuring data integrity





## **No-Data-Loss EDR**

### • **PROBLEM**:

 Conventional flash-based EDRs buffer data into volatile memory and then periodically store into Flash. In the event of a crash, these systems are at risk of losing the last moment critical system data due to instant power failure.

### SOLUTION

• This risk is mitigated when using datalogging memories that enable instant nonvolatile writes





# What is Ferroelectric RAM (F-RAM)

NVM which stores data as a polarization of a ferroelectric material (Lead-Zirconate-Titanate).

As an electric field is applied, dipoles shift in a crystalline structure to store information

### Advantages

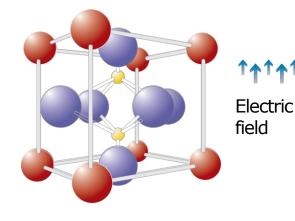
Symmetrical atomic position  $\rightarrow$ Non volatility

Switch in states is instantaneous - Fast writes and Low energy

Based on "atomic position" vs. "trapped charge" → SER immunity and Rediation tolerant

Two symmetrical states with no reason to degrade 📀 Virtually Infinite Endurance Data retention 100 yrs

Cypress' F-RAM is the perfect choice for "Power Efficient, Instantaneous Data-logging"





## Secure F-RAM



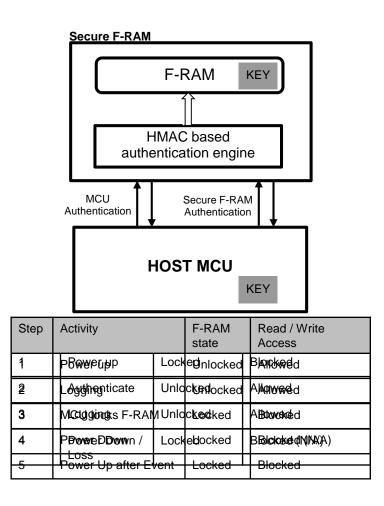


**Problem Statement:** Datalogs containing sensitive personal or legal data may be modified or damaged through malicious intent

**Current Solution:** Limited product ID and serial number–based security; inadequate for malicious attack

### Solution:

- Add authentication protocols to Excelon<sup>TM</sup> F-RAM
  - Option 1; MCU shared key (secure MCU)
  - Option 2: No key on MCU (non-secure MCU)





## **Secure F-RAM Logging Options**

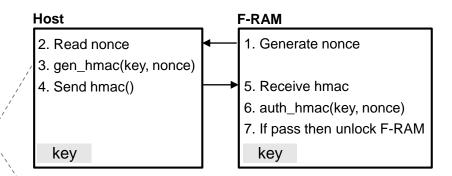
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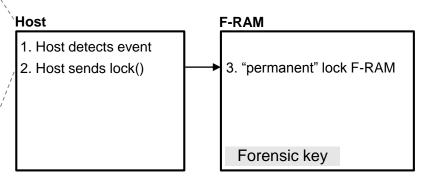
User Option 1 (Shared Key):

Step	Activity	F-RAM state	Read / Write Access
1	Power up	Locked	Blocked
2	Authenticate	Unlocked	Allowed
3	Logging	Unlocked	Allowed
4	Power Down / Loss	Locked	Blocked (N/A)

### User Option 2 (No key on MCU):

Step	Activity	F-RAM state	Read / Write Access
1	Power up	Unlocked	Allowed
2	Logging	Unlocked	Allowed
3	MCU locks F-RAM	Locked	Blocked
4	Power Down	Locked	Blocked (N/A)
5	Power Up after Event	Locked	Blocked

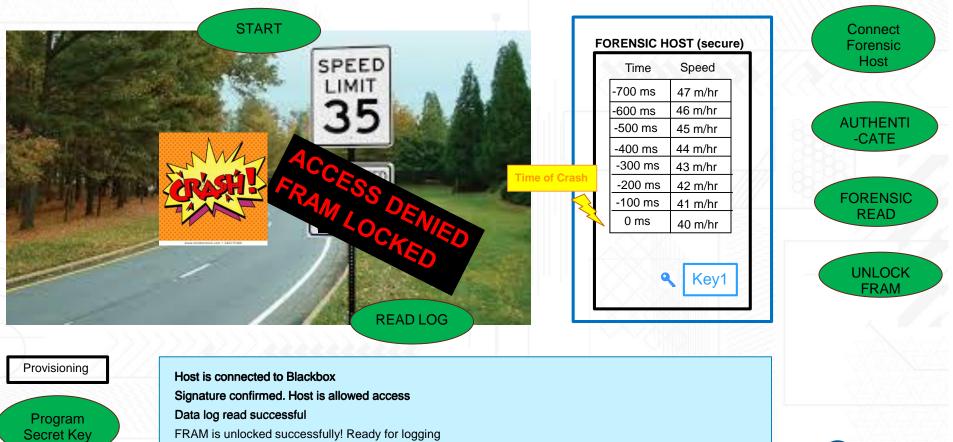




Forensic key is used in lab to retrieve logged data

### Use case: Protect high-value logs in F-RAM

### **SECURE F-RAM DEMO IN EMBEDDED WORLD**







## 2Mb-to-16Mb Excelon™ F-RAM

#### Features

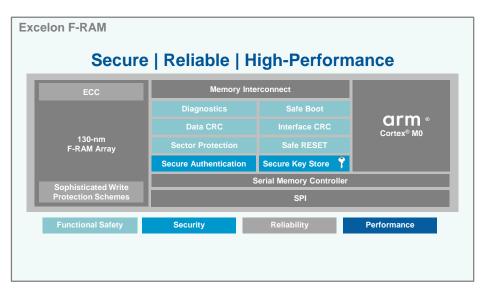
- Excelon-Ultra
- 4Mb
- 108-MHz Single Data Rate (SDR)/54-MHz Double Data Rate (DDR) Quad SPI
- Industrial temperature range: -40°C to +85°C

#### Excelon-Auto

- 2Mb Auto E, 4Mb Auto A
- 50-MHz SPI
- Automotive (AEC-Q100) temperature range grade A: -40°C to +85°C
- Automotive (AEC-Q100) temperature range grade E: -40°C to +125°C

#### Excelon-LP

- 4Mb, 8Mb
- 20-MHz SPI (Commercial), 50-MHz SPI (Industrial)
- Ultra-low (0.10-µA) hibernate current
- Ultra-low (0.75-µA) deep power-down current
- Ultra-low (1.00-µA) standby current
- Commercial temperature range: 0°C to +70°C
- Industrial temperature range: -40°C to +85°C
- Common Features for Excelon-Ultra/Auto/LP
  - Operating voltage range: 1.71–1.89 V, 1.80–3.60 V
  - 100-trillion read/write cycle endurance
  - 100-year data retention



Family Table					
Density	Standby Current (Typ.)	Active Current (Typ.)	Packages		
2Mb	1 µA	3 mA	SOIC (8)		
4Mb	1 µA	3 mA	SOIC (8), GQFN (8)		
8Mb	1 µA	3 mA	GQFN (8)		
16Mb	1 µA	3 mA	SOIC (8), GQNF (8)		



## Thank You!